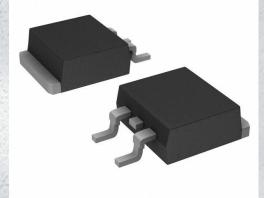


FDB13AN06A0 Datasheet

www.digi-electronics.com



| DiGi Electronics Part Number | FDB13AN06A0-DG |
|------------------------------|--|
| Manufacturer | onsemi |
| Manufacturer Product Number | FDB13AN06A0 |
| Description | MOSFET N-CH 60V 10.9A/62A D2PAK |
| Detailed Description | N-Channel 60 V 10.9A (Ta), 62A (Tc) 115W (Tc) Surf ace Mount TO-263 (D2PAK) |
| | |

https://www.DiGi-Electronics.com



Tel: +00 852-30501935

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Purchase and inquiry

| Manufacturer Product Number: | Manufacturer: |
|---|---|
| FDB13AN06A0 | onsemi |
| Series: | Product Status: |
| PowerTrench® | Active |
| FET Type: | Technology: |
| N-Channel | MOSFET (Metal Oxide) |
| Drain to Source Voltage (Vdss): | Current - Continuous Drain (Id) @ 25°C: |
| 60 V | 10.9A (Ta), 62A (Tc) |
| Drive Voltage (Max Rds On, Min Rds On): | Rds On (Max) @ ld, Vgs: |
| 6V, 10V | 13.5mOhm @ 62A, 10V |
| Vgs(th) (Max) @ ld: | Gate Charge (Qg) (Max) @ Vgs: |
| 4V @ 250μΑ | 29 nC @ 10 V |
| Vgs (Max): | Input Capacitance (Ciss) (Max) @ Vds: |
| ±20V | 1350 pF @ 25 V |
| FET Feature: | Power Dissipation (Max): |
| | 115W (Tc) |
| Operating Temperature: | Mounting Type: |
| -55°C ~ 175°C (TJ) | Surface Mount |
| Supplier Device Package: | Package / Case: |
| ТО-263 (Д2РАК) | TO-263-3, D2PAK (2 Leads + Tab), TO-263AB |
| Base Product Number: | |
| FDB13AN06 | |

Environmental & Export classification

| RoHS Status: | Moisture Sensitivity Level (MSL): |
|------------------|-----------------------------------|
| ROHS3 Compliant | 1 (Unlimited) |
| REACH Status: | ECCN: |
| REACH Unaffected | EAR99 |
| HTSUS: | |
| 8541.29.0095 | |



Is Now Part of

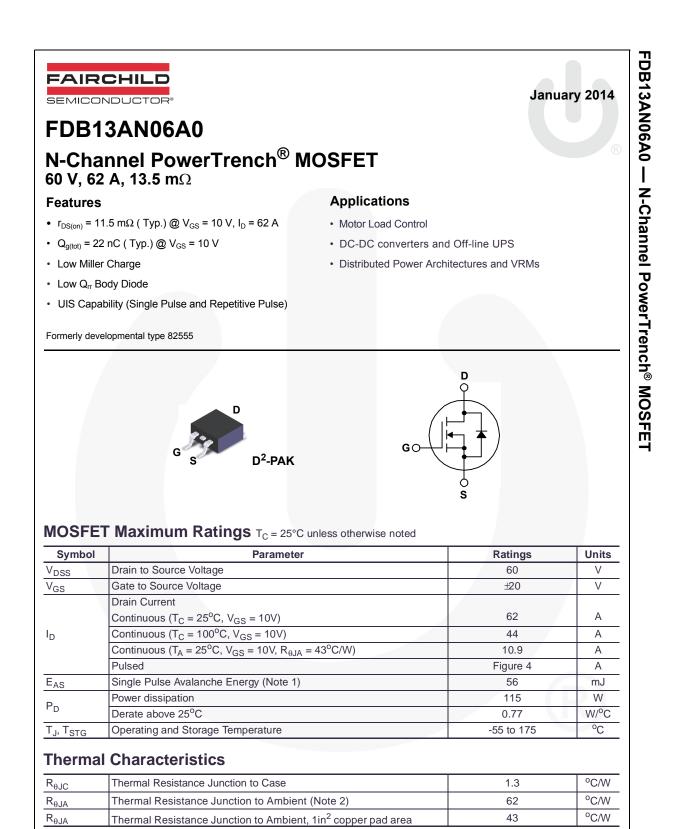


ON Semiconductor®

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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

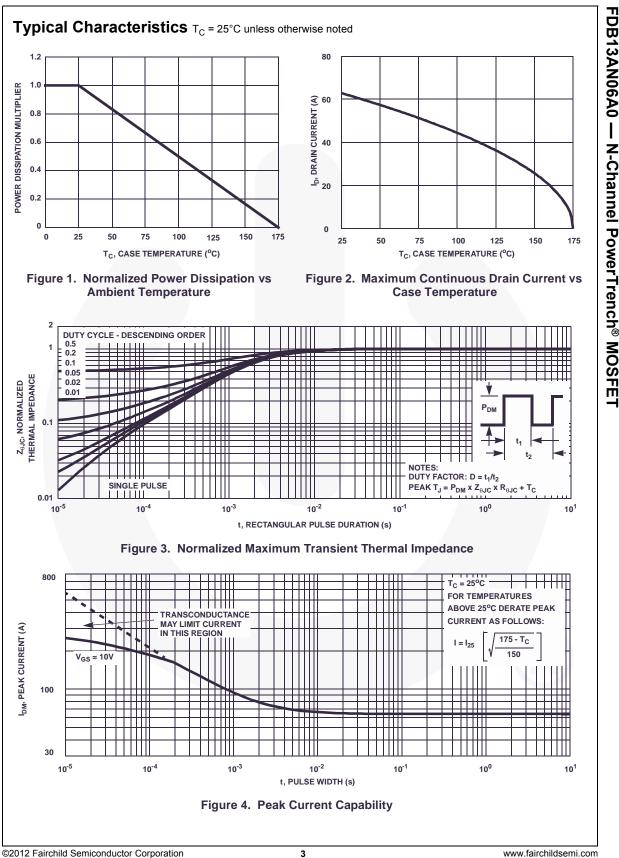
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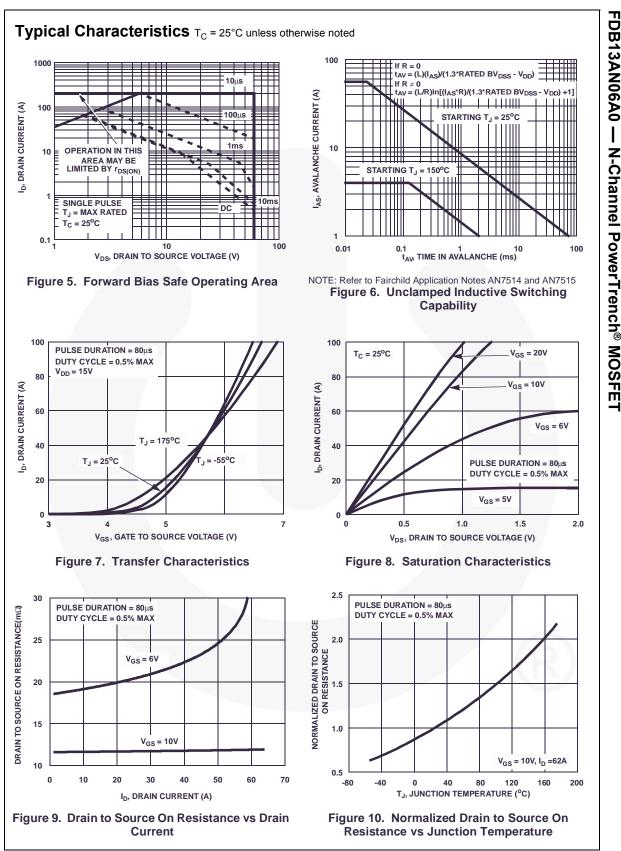
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| Device | Marking | Device | Package | Reel Size | Tape \ | Nidth | Quan | tity | |
|---------------------|-------------------------------|-----------------------------------|--|--|--------|----------|-----------|----------|--|
| FDB13 | BAN06A0 | FDB13AN06A0 | D ² -PAK | 330 mm | 24 mm | | 800 units | | |
| Electri | cal Char | acteristics T _C = 25°C | unless otherwi | se noted | | | | | |
| Symbol | | Parameter | Test | Conditions | Min | Тур | Max | Unit | |
| Off Char | racteristic | s | | | | | | | |
| B _{VDSS} | | Source Breakdown Voltage | 1 - 250 + 1/ = 0 + 1/ | | 60 | - | | V | |
| DVDSS | Diamito C | ource breakdown vollage | $V_{DS} = 50V$ | $I_D = 250\mu A, V_{GS} = 0V$ | | | 1 | v | |
| I _{DSS} | Zero Gate | e Voltage Drain Current | $V_{\rm DS} = 50V$ $V_{\rm GS} = 0V$ | $T_{\rm C} = 150^{\rm o}{\rm C}$ | - | - | 250 | μΑ | |
| I _{GSS} | Gate to S | ource Leakage Current | $V_{GS} = \pm 20V$ | | - | - | ±100 | nA | |
| | | • | | | 1 | 1 | | | |
| On Char | racteristic | S | | | | | | | |
| V _{GS(TH)} | Gate to S | ource Threshold Voltage | $V_{GS} = V_{DS},$ | | 2 | - | 4 | V | |
| | | | I _D = 62A, V _C | | - | 0.0115 | 0.0135 | | |
| r _{DS(ON)} | Drain to S | Source On Resistance | I _D = 31A, V _C | | - | 0.022 | 0.034 | Ω | |
| 20(011) | | | I _D = 62A, V _C T _J = 175°C | _{GS} = 10V, | - | 0.026 | 0.030 | | |
| | | | | | | 1 | | | |
| | c Characte | | | | | | | | |
| C _{ISS} | Input Cap | | V _{DS} = 25V, | $V_{00} = 0 V$ | - | 1350 | - | pF | |
| C _{OSS} | | apacitance | f = 1MHz | ·GS = •••, | - | 260 | - | pF | |
| C _{RSS} | | Transfer Capacitance | | | - | 90 | - | pF | |
| Q _{g(TOT)} | | e Charge at 10V | $V_{GS} = 0V to$ | | | 22 | 29 | nC | |
| Q _{g(TH)} | | Gate Charge | $V_{GS} = 0V$ to | $2V$ $V_{DD} = 30V$ | - | 2.6 | 3.4 | nC | |
| Q _{gs} | | ource Gate Charge | | I _D = 62A I _g = 1.0mA | - | 8.5 | - | nC | |
| Q _{gs2} | | rge Threshold to Plateau | | ig = 1.0mA | - | 5.9 | - | nC | |
| Q _{gd} | | rain "Miller" Charge | | _ | - | 6.4 | - | nC | |
| | | teristics (V _{GS} = 10V) | | | 1 | | i | | |
| t _{ON} | Turn-On T | | | | - | - | 158 | ns | |
| t _{d(ON)} | | Delay Time | | | - | 9 | - | ns | |
| t _r | Rise Time | | $V_{DD} = 30V,$ $V_{GS} = 10V,$ | | - | 96 | - | ns | |
| t _{d(OFF)} | | Delay Time | $v_{GS} = 10V,$ | NGS - 1232 | - | 24 26 | - | ns | |
| t _f | Fall Time Turn-Off 1 | Time | _ | | - | 20 | - 74 | ns ns | |
| t _{OFF} | | | | | - | 1 - | 74 | 115 | |
| Drain-So | ource Dio | de Characteristics | | | | | | | |
| Van | Source to | Source to Drain Diade Valtage | $I_{SD} = 62A$ | | - | - | 1.25 | V | |
| V _{SD} | Source to Drain Diode Voltage | | I _{SD} = 31A | | - / | - | 1.0 | V | |
| t _{rr} | | Recovery Time | $I_{SD} = 62A$, $dI_{SD}/dt = 100A/\mu s$ | | - | - | 25 | ns | |
| Q _{RR} | Reverse F | Recovered Charge | I _{SD} = 62A, c | ll _{SD} /dt = 100A/μs | - | - | 17 | nC | |

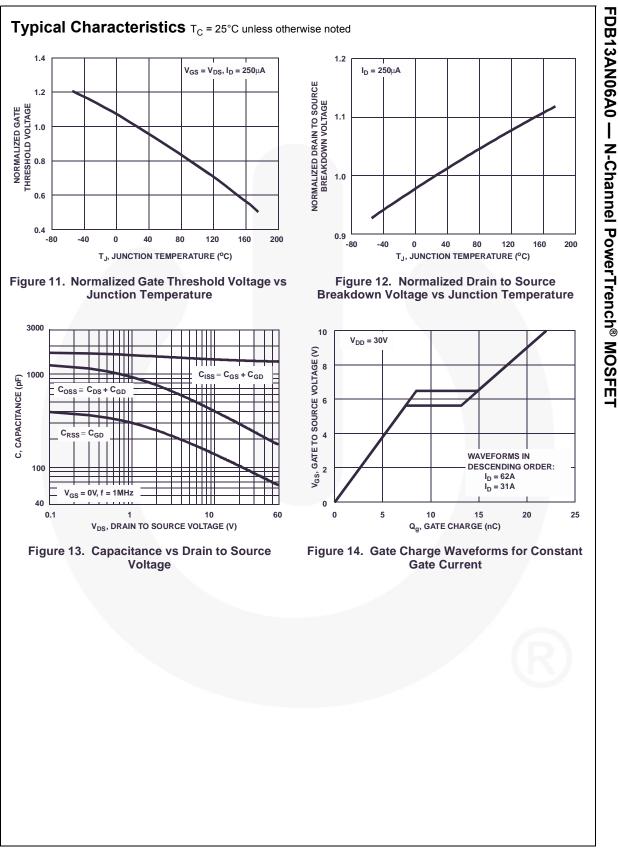
FDB13AN06A0 — N-Channel PowerTrench® MOSFET

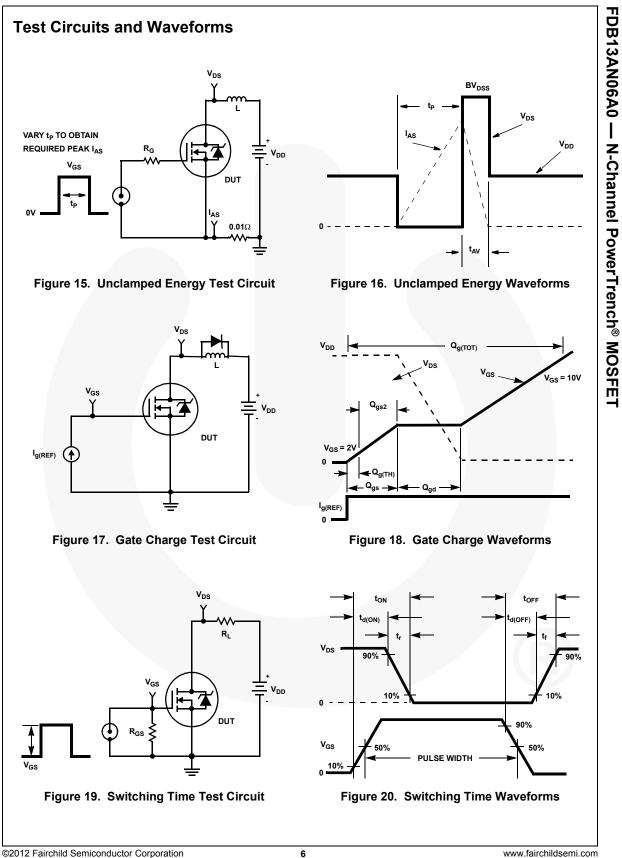


FDB13AN06A0 Rev. C2



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Thermal Resistance vs. Mounting Pad Area

The maximum rated junction temperature, T_{JM} , and the thermal resistance of the heat dissipating path determines the maximum allowable device power dissipation, P_{DM} , in an application. Therefore the application's ambient temperature, T_A (°C), and thermal resistance $R_{\theta JA}$ (°C/W) must be reviewed to ensure that T_{JM} is never exceeded. Equation 1 mathematically represents the relationship and serves as the basis for establishing the rating of the part.

$$P_{DM} = \frac{(T_{JM} - T_A)}{R_{\theta JA}}$$
(EQ. 1)

In using surface mount devices such as the TO-263 package, the environment in which it is applied will have a significant influence on the part's current and maximum power dissipation ratings. Precise determination of P_{DM} is complex and influenced by many factors:

- Mounting pad area onto which the device is attached and whether there is copper on one side or both sides of the board.
- 2. The number of copper layers and the thickness of the board.
- 3. The use of external heat sinks.
- 4. The use of thermal vias.
- 5. Air flow and board orientation.
- 6. For non steady state applications, the pulse width, the duty cycle and the transient thermal response of the part, the board and the environment they are in.

Fairchild provides thermal information to assist the designer's preliminary application evaluation. Figure 21 defines the $R_{\theta JA}$ for the device as a function of the top copper (component side) area. This is for a horizontally positioned FR-4 board with 1oz copper after 1000 seconds of steady state power with no air flow. This graph provides the necessary information for calculation of the steady state junction temperature or power dissipation. Pulse applications can be evaluated using the Fairchild device Spice thermal model or manually utilizing the normalized maximum transient thermal impedance curve.

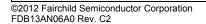
Thermal resistances corresponding to other copper areas can be obtained from Figure 21 or by calculation using Equation 2 or 3. Equation 2 is used for copper area defined in inches square and equation 3 is for area in centimeters square. The area, in square inches or square centimeters is the top copper area including the gate and source pads.

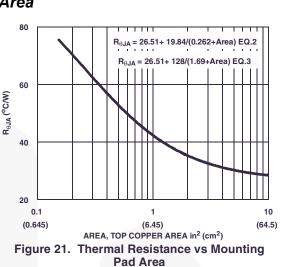
$$R_{\theta JA} = 26.51 + \frac{19.84}{(0.262 + Area)}$$
(EQ. 2)

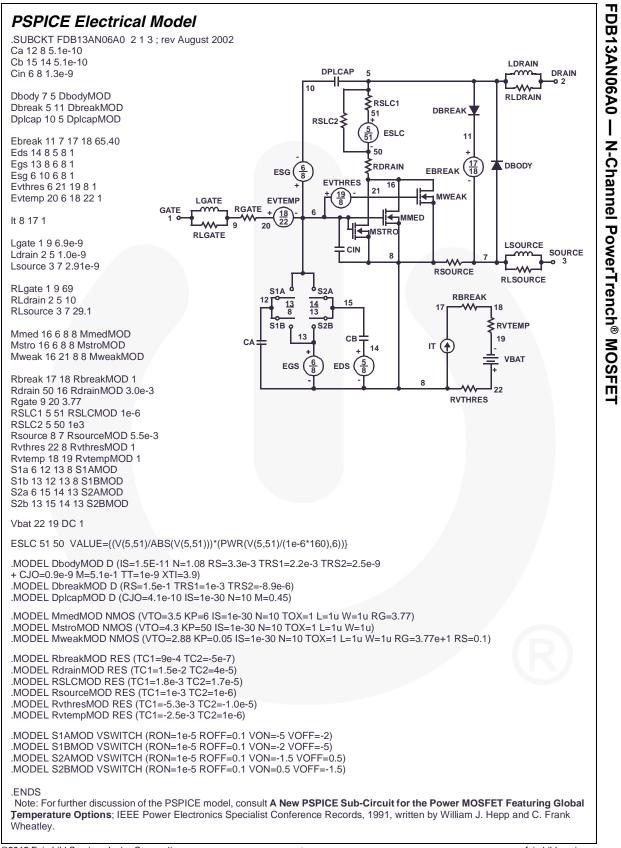
Area in Inches Squared

$$R_{\theta JA} = 26.51 + \frac{128}{(1.69 + Area)}$$
 (EQ. 3)

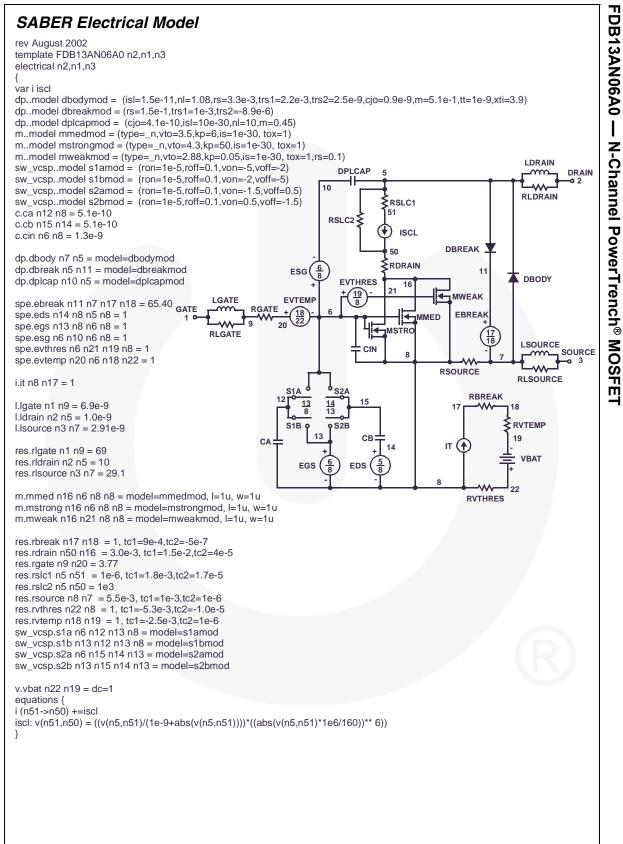
Area in Centimeters Squared

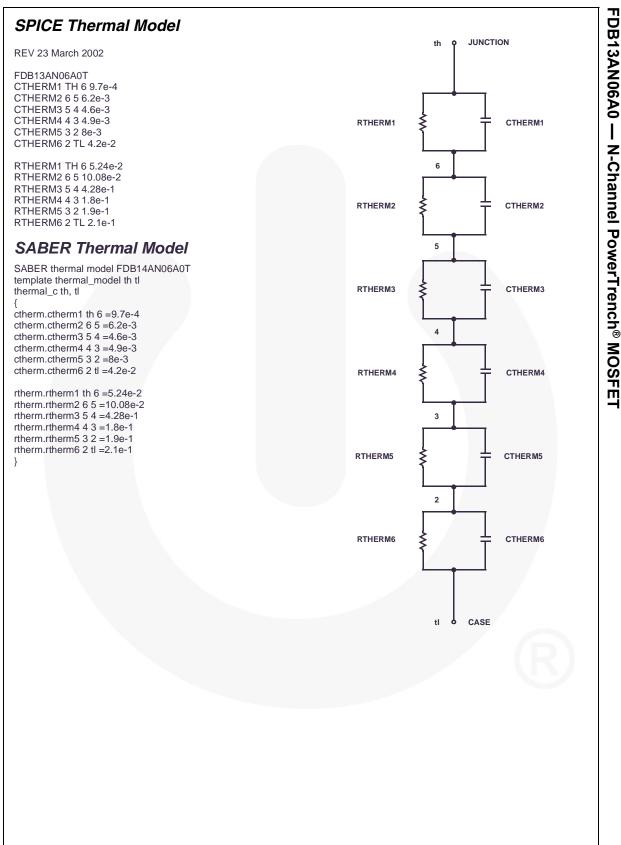


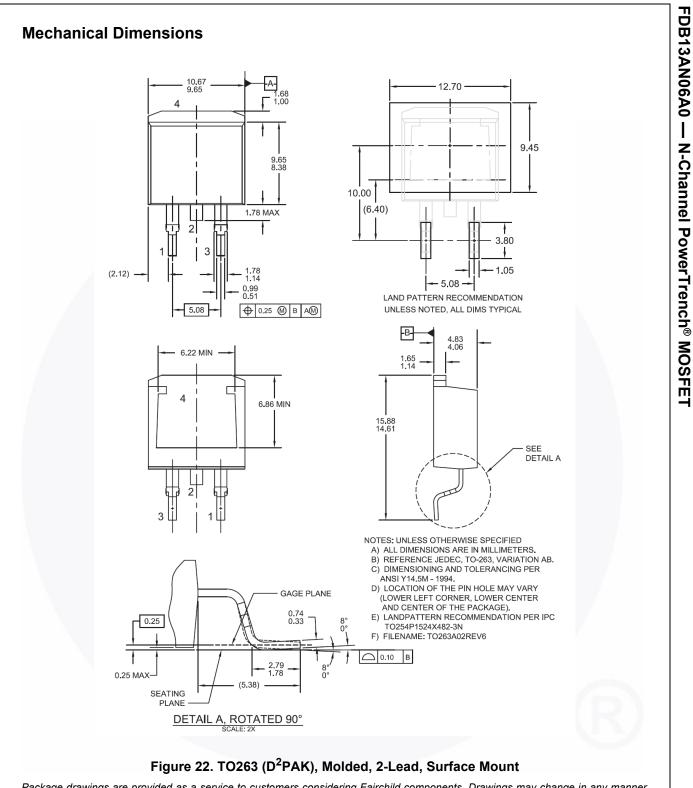




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Not In Production

Obsolete

Datasheet contains specifications on a product that is discontinued by Fairchild

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Rev 166

FDB13AN06A0 onsemi MOSFET N-CH 60V 10.9A/62A D2PAK

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